

# Shenzhen ZhongjianNanfang Testing Co., Ltd.

Report No:CCISE191111701

# FCC REPORT

Applicant: Prometheus Group LLC

Address of Applicant: P.O. Box 130100 birmingham, Alabama 35213-0100 USA.

**Equipment Under Test (EUT)** 

Product Name: Hunting Camera

Model No.: BTC-DWC-VZW. BTC-SFW-VZW

Trade mark: BROWNING

FCC ID: 2ALGTBTC-DWC-VZW

FCC CFR Title 47 Part 2

Applicable standards: FCC CFR Title 47 Part 27 Subpart L

FCC CFR Title 47 Part 27 Subpart E

Date of sample receipt: 19 Nov., 2019

**Date of Test:** 20 Nov., to 09 Dec., 2019

Date of report issued: 10 Dec., 2019

Test Result: PASS\*

#### Authorized Signature:



Bruce Zhang Laboratory Manager

This report details the results of the testing carried out on one sample. The results contained in this test report do not relate to other samples of the same product and does not permit the use of the CCIS product certification mark. The manufacturer should ensure that all products in series production are in conformity with the product sample detailed in this report.

This report may only be reproduced and distributed in full. If the product in this report is used in any configuration other than that detailed in the report, the manufacturer must ensure the new system complies with all relevant standards.

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<sup>\*</sup>In the configuration tested, the EUT complied with the standards specified above.

Report No: CCISE191111701



#### 2. Version

Version No.	Date	Description
00	10 Dec., 2019	Original

Tanet Wei Date:

Test Engineer

Winner Many Date: Tested by: 10 Dec., 2019

Reviewed by: 10 Dec., 2019

**Project Engineer** 



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## 4. Test Summary

Test Items	Section in CFR 47	Result
RF Exposure (SAR)	Part 1.1307	Passed
KF Exposure (SAK)	Part 2.1093	(Please refer toSAR Report)
	Part 2.1046	
RF Output Power	Part 27.50 (d)(4)	Pass
	Part 27.50 (b)(10)	
Peak-to-Average Ratio	Part 27.50(d)(5)	Pass
Modulation Characteristics	Part 2.1047	Pass
	Part 2.1049	
99% & -26 dB Occupied Bandwidth	Part 27.53(h)	Pass
	Part 27.53(c)	
Out of board emission at automa	Part 2.1053	
Out of band emission at antenna terminals	Part 27.53 (h)	Pass
terriirais	Part 27.53(c)	
Field atropath of anurious radiation	Part 27.53 (h)	Pass
Field strength of spurious radiation	Part 27.53(c)(f)	Pass
Fragues of a tability was to magaziture	Part 27.54	Door
Frequency stability vs. temperature	Part 2.1055(a)(1)(b)	Pass
Fraguerou etabilitu va valtara	Part 27.54	Door
Frequency stability vs. voltage	Part 2.1055(d)(2)	Pass

#### Remark:

Test Method: ANSI/TIA-603-E-2016 ANSI C63.26-2015

<sup>1.</sup> Pass: The EUT complies with the essential requirements in the standard.

<sup>2.</sup> The cable insertion loss used by "RF Output Power" and other conduction measurement items is 0.5dB (provided by the customer).



## 5. General Information

### **5.1 Client Information**

Applicant:	Prometheus Group LLC	
Address:	P.O. Box 130100 birmingham, Alabama 35213-0100 USA.	
Manufacturer:	Systech Electronics Limited	
Address:	Unit 802, 8/F, Sunbeam Centre, 27 Shing Yip Street, Kwun Tong, Kowloon, Hong Kong.	

5.2 General Description of E.U.T.

3.2 General Description	OI E.O.1.
Product Name:	Hunting Camera
Model No.:	BTC-DWC-VZW, BTC-SFW-VZW
Operation Frequency range:	LTE Band 4:TX: 1710MHz-1755MHz, RX: 2110MHz-2155MHz LTE Band 13: TX:777MHz-787MHz, RX: 746MHz-756MHz
Modulation type:	QPSK, 16QAM
Antenna type:	Internal Antenna
Antenna gain:	LTE Band4:1.93dBi LTE Band 13:1.03dBi
Power supply:	DC12V OR POWER SOURCE: 8x1.5AA x 2 Battery
Test Sample Condition:	The applicant provided engineering samples for staying in continuously transmitting for testing.
Remark:	The No.: BTC-DWC-VZW, BTC-SFW-VZW were identical inside, the electrical circuit design, layout, components used and internal wiring, with only model number is different for the marketing requirement.



#### **Operation Frequency List:**

LTE Band 4(1.4MHz)		LTE Band 4(3MHz)		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
19957	1710.70	19965	1711.50	
19958	1710.80	19966	1711.60	
20174	1732.40	20174	1732.40	
20175	1732.50	20175	1732.50	
20176	1732.60	20176	1732.60	
•••	***		•••	
20392	1754.20	20384	1753.40	
20393	1754.30	20385	1753.50	
LTE Band	I 4(5MHz)	LTE Band	4(10MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
19975	1712.50	20000	1715.00	
19976	1712.60	20001	1715.10	
20174	1732.40	20174	1732.40	
20175	1732.50	20175	1732.50	
20176	1732.60	20176	1732.60	
	***			
20374	1752.40	20349	1749.90	
20375	1752.50	20350	1750.00	
LTE Band	4(15MHz)	LTE Band 4(20MHz)		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
20025	1717.50	20050	1720.00	
20026	1717.60	20051	1720.10	
20174	1732.40	20174	1732.40	
20175	1732.50	20175	1732.50	
20176	1732.60	20176	1732.60	
20324	1747.40	20299	1744.90	
20325	1747.50	20300	1745.00	

LTE Band 13(5MHz)		LTE Band 13(10MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
23205	779.50	1	/
23206	779.60	1	/
		1	/
23229	781.90	1	/
23230	782.00	23230	782.00
23231	782.10	1	/
***		1	/
23255	784.50	1	/
23256	784.60	1	/



Regards to the operating frequency range, the lowest frequency, the middle frequency, and the highest frequency of channel were selected to perform the test, and the selected channels as below:

LTE Band 4(1.4MHz)		LTE Band 4(3MHz)			
Channe	el:	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	19957	1710.70	Lowest channel	19965	1711.50
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20393	1754.30	Highest channel	20385	1753.50
L7	LTE Band 4(5MHz)		LTE Band 4(10MHz)		
Chann	el	Frequency (MHz)	Channe	I	Frequency (MHz)
Lowest channel	19975	1712.50	Lowest channel	20000	1715.00
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20375	1752.50	Highest channel	20350	1750.00
LTE Band 4(15MHz)		LTE	Band 4(20M	Hz)	
Chann	el	Frequency (MHz)	Channe	I	Frequency (MHz)
Lowest channel	20025	1717.50	Lowest channel	20050	1720.00
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20325	1747.50	Highest channel	20300	1745.00

LTE Band 13(5MHz)		LTE Band 13(10MHz)			
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	23205	779.5	Lowest channel	/	/
Middle channel	23230	782.0	Middle channel	23230	782.00
Highest channel	23255	784.5	Highest channel	/	/



#### 5.3 Test environment and mode

Operating Environment:			
Temperature:	Normal: 15 °C ~ 35 °C, Extreme: -30 °C ~ +50 °C		
Humidity:	20 % ~ 75 % RH		
Atmospheric Pressure:	1008 mbar		
Voltage:	Nominal: 12Vdc, Extreme: Low 11.2Vdc, High 12.8Vdc		
Test mode:			
LTE QPSKmode	Keep the EUT communication with simulated station in QPSK mode		
LTE 16-QAMmode	Keep the EUT communication with simulated station in 16-QAM mode		
Remark: The EUT has be	Remark: The EUT has been tested undercontinuous transmitting mode. Channel Low, Mid and High for		

Remark: The EUT has been tested undercontinuous transmitting mode. Channel Low, Mid and High for each type band with rated data rate were chosen for full testing. The field strength of spurious radiation emission was measured as EUT stand-up position (H mode) and lie down position (E1, E2 mode) for these modes with power adaptor, earphone and Data cable. Just the worst case position (H mode) shown in report.

5.4 Description of Support Units

Test Equipment	Manufacturer	Model No.	Serial No.
Simulated Station	Anritsu	MT8820C	6201026545

#### 5.5 Measurement Uncertainty

Parameters	Expanded Uncertainty
Radiated Emission (9kHz ~ 30MHz)	±3.12 dB (k=2)
Radiated Emission (30MHz ~ 1000MHz)	±4.32 dB (k=2)
Radiated Emission (1GHz ~ 18GHz)	±5.38 dB (k=2)
Radiated Emission (18GHz ~ 40GHz)	±3.36 dB (k=2)

#### 5.6 Related Submittal(s) / Grant (s)

Thisis an original grant, no related submittals and grants.

#### 5.7 Additions to, deviations, or exclusions from the method

No

#### 5.8 Laboratory Facility

The test facility is recognized, certified, or accredited by the following organizations:

#### • FCC - Designation No.: CN1211

Shenzhen ZhongjianNanfang Testing Co., Ltd. has been accredited as a testing laboratory byFCC (Federal Communications Commission). The test firm Registration No. is 727551.

#### • ISED-CAB identifier.: CN0021

The 3m Semi-anechoic chamber of Shenzhen ZhongjianNanfang Testing Co., Ltd. has been Registered by Certification and Engineering Bureau of Industry Canada for radio equipment testing with Registration No.: 10106A-1.

#### CNAS - Registration No.: CNAS L6048

Shenzhen ZhongjianNanfang Testing Co., Ltd. is accredited to ISO/IEC 17025:2005 General Requirements for the Competence of Testing and Calibration laboratories for the competence of testing. The Registration No. is CNAS L6048.

#### A2LA - Registration No.: 4346.01

This laboratory is accredited in accordance with the recognized International Standard ISO/IEC 17025:2005General requirements for the competence of testing and calibration laboratories. The test scope can be found as below link: <a href="https://portal.a2la.org/scopepdf/4346-01.pdf">https://portal.a2la.org/scopepdf/4346-01.pdf</a>



## **5.9 Laboratory Location**

Shenzhen ZhongjianNanfang Testing Co., Ltd. Address: No.B-C, 1/F., Building 2, Laodong No.2 Industrial Park, Xixiang Road,

Bao'an District, Shenzhen, Guangdong, China Tel: +86-755-23118282, Fax:+86-755-23116366

Email: info@ccis-cb.com, Website: http://www.ccis-cb.com

#### 5.10 Test Instruments list

Test Equipment	Manufacturer	Model No.	Serial No.	Cal.Date (mm-dd-yy)	Cal.Due date (mm-dd-yy)
3m SAC	SAEMC	9m*6m*6m	966	07-22-2017	07-21-2020
BiConiLog Antenna	SCHWARZBECK	VULB9163	497	03-18-2019	03-17-2020
Biconical Antenna	SCHWARZBECK	VUBA9117	359	06-22-2017	06-21-2020
Horn Antenna	SCHWARZBECK	BBHA9120D	916	03-18-2019	03-17-2020
Horn Antenna	SCHWARZBECK	BBHA9120D	1805	06-22-2017	06-21-2020
Horn Antenna	SCHWARZBECK	BBHA 9170	BBHA9170582	11-21-2019	11-20-2020
EMI Test Software	AUDIX	E3	V	ersion: 6.110919	b
Pre-amplifier	HP	8447D	2944A09358	03-18-2019	03-17-2020
Pre-amplifier	CD	PAP-1G18	11804	03-18-2019	03-17-2020
Spectrum analyzer	Rohde & Schwarz	FSP30	101454	03-18-2019	03-17-2020
EMI Test Receiver	Rohde & Schwarz	ESRP7	101070	03-18-2019	03-17-2020
Spectrum Analyzer	Agilent	N9020A	MY50510123	10-29-2019	10-28-2020
Signal Generator	Rohde & Schwarz	SMX	835454/016	03-18-2019	03-17-2020
Signal Generator	R&S	SMR20	1008100050	03-18-2019	03-17-2020
RF Switch Unit	MWRFTEST	MW200	N/A	N/A	N/A
Test Software	MWRFTEST	MTS8200		Version: 2.0.0.0	
Cable	ZDECL	Z108-NJ-NJ-81	1608458	03-18-2019	03-17-2020
Cable	MICRO-COAX	MFR64639	K10742-5	03-18-2019	03-17-2020
Cable	SUHNER	SUCOFLEX100	58193/4PE	03-18-2019	03-17-2020
DC Power Supply	XinNuoEr	WYK-10020K	1409050110020	10-31-2019	10-30-2020
Temperature Humidity Chamber	HengPu	HPGDS-500	20140828008	09-24-2019	09-23-2020
Simulated Station	Rohde & Schwarz	CMW500	140493	07-16-2019	07-15-2020



## 6. Test results

## 6.1 Conducted Output Power, ERP and EIRP

Test Requirement:	Part 27.50(d)(4), Part 27.50 (b)(10)				
Limit:	LTE Band 4: 1W, LTE Band 13: 3W				
Test Setup:	System simulator ATT EUT				
Test Procedure:	The transmitter output was connected to a calibrated attenuator, the other end of which was connected to the CMW500. Transmitter output power was read off in dBm.				
Test Instruments:	Refer to section 5.10 for details				
Test mode:	Refer to section 5.3 for details				
Test results:	Passed				



#### **Measurement Data:**

					Ave	rage Power (dl	Bm)
LTE Band	Bandwidth	Modulation	RB Size	RB Offset	19957	20175	20393
2.2 24.14	(MHz)	Moderation	112 0.20	112 011001	1710.7MHz	1732.5MHz	1754.3MHz
			1	0	22.37	22.31	22.18
			1	2	22.41	22.28	22.08
			1	5	22.47	22.22	21.85
		QPSK	3	0	22.34	22.27	22.09
		Q. O.	3	1	22.36	22.31	22.05
			3	2	22.39	22.28	22.08
			6	0	21.36	21.35	21.12
		Ante	nna Gain(dE			1.93	
			c. EIRP (dBm			24.40	
			P Limit (dBm	·		30.00	
4	1.4		1	0	21.72	21.91	21.64
			1	2	21.75	21.80	21.51
			1	5	21.76	21.73	21.43
		16QAM	3	0	21.49	21.52	21.53
			3	1	21.53	21.51	21.45
			3	2	21.81	21.61	21.41
			6	0	20.41	20.28	20.20
		Antenna Gain(dBi):			1.93		
			c. EIRP (dBm			23.84	
			P Limit (dBm	·		30.00	
	D - 1 144				Ave	rage Power (dl	3m)
LTE Band	Bandwidth	Modulation	RB Size	RB Size RB Offset	19965	20175	20385
	(MHz)				1711.5MHz	1732.5MHz	1753.5MHz
			1	0	22.81	22.67	23.47
			1	7	23.12	22.72	23.41
			1	14	23.16	22.65	23.11
		QPSK	8	0	22.04	21.60	22.37
			8	4	22.15	21.56	22.41
			8	7	22.25	21.58	22.23
			15	0	22.03	21.51	22.21
		Ante	nna Gain(dE	Bi):		1.93	
			c. EIRP (dBm			25.40	
4	3	EIR	P Limit (dBm	n):		30.00	
4	S		1	0	22.38	22.03	22.74
			1	7	22.57	22.28	22.84
			1	14	22.72	22.15	22.48
		16QAM	8	0	21.16	20.73	21.57
			8	4	21.22	20.81	21.54
			8	7	21.15	20.73	21.41
			15	0	21.04	20.59	21.40
		Ante	nna Gain(dE	Bi):		1.93	
		Max	c. EIRP (dBm	n):		24.77	
		EIR	P Limit (dBm	n):		30.00	
Note: EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi).							



					Ave	rage Power (dl	3m)
LTE Band	Bandwidth	Modulation	RB Size	RB Offset	19975	20175	20375
	(MHz)		. 12 0.20		1712.5MHz	1732.5MHz	1752.5MHz
			1	0	22.53	22.44	22.96
			1	12	22.96	22.72	22.97
			1	24	22.74	22.24	22.18
		QPSK	12	0	21.96	21.63	22.02
		Q. 011	12	6	21.94	21.72	22.01
			12	11	21.93	21.63	21.79
			25	0	21.85	21.53	21.89
		Ante	nna Gain(dE	3i):		1.93	
			c. EIRP (dBn			24.90	
	_		P Limit (dBn			30.00	
4	5		1	ĺ O	21.91	21.86	22.24
			1	12	22.49	21.87	22.27
			1	24	21.98	21.57	21.86
		16QAM	12	0	20.83	20.64	20.99
			12	6	20.95	20.55	21.04
			12	11	20.97	20.58	20.85
			25	0	20.82	20.55	20.87
		Antenna Gain(dBi):			1.93		
		Max. EIRP (dBm):				24.42	
			P Limit (dBn			30.00	
				ı			
	Bandwidth		DD 0:	55.6%	Average Power (dBm)		
LTE Band							
LIL Bana	(MHz)	Modulation	RB Size	RB Offset	20000	20175	20350
ETE Baria	(MHz)	Modulation			1715.0MHz	1732.5MHz	1750.0MHz
ETE Bana	(MHz)	Modulation	1	0	1715.0MHz 22.35	1732.5MHz 23.15	1750.0MHz 23.71
ETE Balla	(MHz)	Modulation	1 1	0 24	1715.0MHz 22.35 23.01	1732.5MHz 23.15 23.50	1750.0MHz 23.71 24.32
ETE Balla	(MHz)		1 1 1	0 24 49	1715.0MHz 22.35 23.01 22.28	1732.5MHz 23.15 23.50 22.75	1750.0MHz 23.71 24.32 23.23
ETE Balla	(MHz)	QPSK	1 1 1 25	0 24 49 0	1715.0MHz 22.35 23.01 22.28 21.77	1732.5MHz 23.15 23.50 22.75 22.13	1750.0MHz 23.71 24.32 23.23 22.98
ETE Balla	(MHz)		1 1 1 25 25	0 24 49 0 12	1715.0MHz 22.35 23.01 22.28 21.77 21.89	1732.5MHz 23.15 23.50 22.75 22.13 22.08	1750.0MHz 23.71 24.32 23.23 22.98 23.07
	(MHz)		1 1 1 25 25 25	0 24 49 0 12 24	1715.0MHz 22.35 23.01 22.28 21.77 21.89 21.73	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87	1750.0MHz 23.71 24.32 23.23 22.98 23.07 22.79
	(MHz)	QPSK	1 1 1 25 25 25 25 50	0 24 49 0 12 24	1715.0MHz 22.35 23.01 22.28 21.77 21.89	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53	1750.0MHz 23.71 24.32 23.23 22.98 23.07
	(MHz)	QPSK	1 1 1 25 25 25 25 50 enna Gain(dE	0 24 49 0 12 24 0	1715.0MHz 22.35 23.01 22.28 21.77 21.89 21.73	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93	1750.0MHz 23.71 24.32 23.23 22.98 23.07 22.79
	(MHz)	QPSK Ante	1 1 1 25 25 25 25 50 enna Gain(dB	0 24 49 0 12 24 0 8i):	1715.0MHz 22.35 23.01 22.28 21.77 21.89 21.73	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25	1750.0MHz 23.71 24.32 23.23 22.98 23.07 22.79
4	(MHz)	QPSK Ante	1 1 1 25 25 25 25 50 enna Gain(dE	0 24 49 0 12 24 0 3i):	1715.0MHz 22.35 23.01 22.28 21.77 21.89 21.73 21.70	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00	1750.0MHz 23.71 24.32 23.23 22.98 23.07 22.79 22.81
		QPSK Ante	1 1 25 25 25 25 50 enna Gain(dBn C. EIRP (dBn P Limit (dBn	0 24 49 0 12 24 0 3i):	22.35 23.01 22.28 21.77 21.89 21.73 21.70	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45	1750.0MHz 23.71 24.32 23.23 22.98 23.07 22.79 22.81
		QPSK Ante	1 1 25 25 25 50 enna Gain(dE c. EIRP (dBn P Limit (dBn 1	0 24 49 0 12 24 0 3i):	22.35 23.01 22.28 21.77 21.89 21.73 21.70	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72
		QPSK  Ante  Max  EIR	1 1 25 25 25 50 enna Gain(dE c. EIRP (dBn P Limit (dBn 1 1	0 24 49 0 12 24 0 3i): n): n):	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67
		QPSK Ante	1 1 25 25 25 50 enna Gain(dE c. EIRP (dBn 1 1 1 1 25	0 24 49 0 12 24 0 8i): n): n): 24 49	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77 21.23	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20 21.22	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67 21.49
		QPSK  Ante  Max  EIR	1 1 25 25 25 50 enna Gain(dBa c. EIRP (dBa P Limit (dBa 1 1 1 1 25 25	0 24 49 0 12 24 0 8i): n): n): 0 24 49 0	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77 21.23 21.47	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20 21.22 21.16	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67 21.49 21.62
		QPSK  Ante  Max  EIR	1 1 25 25 25 50 enna Gain(dE c. EIRP (dBn P Limit (dBn 1 1 1 25 25 25	0 24 49 0 12 24 0 8i): n): n): 10 24 49 0 12 24	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77 21.23	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20 21.22	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67 21.49
		QPSK  Ante  Max  EIR  16QAM	1 1 25 25 25 50 enna Gain(dE c. EIRP (dBn P Limit (dBn 1 1 1 1 25 25 25 50	0 24 49 0 12 24 0 3i): n): 0 24 49 0 12 24 0	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77 21.23 21.47	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20 21.22 21.16 21.02	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67 21.49 21.62
		QPSK  Ante  Max EIR  16QAM	1 1 25 25 25 50 nna Gain(dE c. EIRP (dBn 1 1 1 1 25 25 25 50	0 24 49 0 12 24 0 3i): n): n): 24 49 0 12 24 0 3i):	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77 21.23 21.47	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20 21.22 21.16 21.02 / 1.93	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67 21.49 21.62
		Ante Max EIR 16QAM	1 1 25 25 25 50 enna Gain(dE c. EIRP (dBn 1 1 1 1 25 25 25 50 enna Gain(dE c. EIRP (dBn	0 24 49 0 12 24 0 8i): n): n): 0 24 49 0 12 24 0 8i):	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77 21.23 21.47	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20 21.22 21.16 21.02 / 1.93 25.65	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67 21.49 21.62
4	10	Ante Max EIR 16QAM	1 1 25 25 25 50 enna Gain(dEx. EIRP (dBn 1 1 25 25 25 50 enna Gain(dEx. EIRP (dBn 1 1 1 25 25 25 50 enna Gain(dEx. EIRP (dBn	0 24 49 0 12 24 0 8i): n): n): 12 24 49 0 12 24 0 8i): n):	22.35 23.01 22.28 21.77 21.89 21.73 21.70 21.93 22.33 21.77 21.23 21.47	1732.5MHz 23.15 23.50 22.75 22.13 22.08 21.87 22.53 1.93 26.25 30.00 22.45 22.73 22.20 21.22 21.16 21.02 / 1.93	23.71 24.32 23.23 22.98 23.07 22.79 22.81 22.92 23.72 22.67 21.49 21.62



	D1-199				Ave	erage Power (dl	Bm)
LTE Band	Bandwidth	Modulation	RB Size	RB Offset	20025	20175	20325
	(MHz)				1717.5MHz	1732.5MHz	1747.5MHz
			1	0	23.83	23.87	22.82
			1	37	23.72	23.72	22.87
			1	74	23.45	23.71	23.02
		QPSK	36	0	22.95	22.59	22.75
		Q. O.	36	16	22.81	22.55	23.45
			36	35	22.46	22.35	24.22
			75	0	22.65	22.44	23.83
		Ante	nna Gain(dE	_	22.00	1.93	20.00
			. EIRP (dBn			26.15	
			P Limit (dBm			30.00	
4	15	2	1	0	23.54	23.26	23.42
			1	37	23.38	23.15	23.74
			1	74	23.08	23.39	23.22
		16QAM	36	0	/	/	/
			36	16	/		/
			36	35	/		,
			75	0	/	/	/
		Antenna Gain(dBi):			1.93		
			. EIRP (dBm			25.67	
			P Limit (dBm			30.00	
	L			,			
						5 / 1	<b>-</b> \
	Bandwidth		DD 6:	DD 0" 1		erage Power (di	
LTE Band	Bandwidth (MHz)	Modulation	RB Size	RB Offset	20050	20175	20300
LTE Band	Bandwidth (MHz)	Modulation			20050 1720.0MHz	20175 1732.5MHz	20300 1745.0MHz
LTE Band		Modulation	1	0	20050 1720.0MHz 24.17	20175 1732.5MHz 23.87	20300 1745.0MHz 24.02
LTE Band		Modulation	1 1	0 49	20050 1720.0MHz 24.17 23.27	20175 1732.5MHz 23.87 23.22	20300 1745.0MHz 24.02 23.67
LTE Band			1 1 1	0 49 99	20050 1720.0MHz 24.17 23.27 23.75	20175 1732.5MHz 23.87 23.22 23.93	20300 1745.0MHz 24.02 23.67 23.75
LTE Band		Modulation QPSK	1 1 1 50	0 49 99 0	20050 1720.0MHz 24.17 23.27 23.75 22.73	20175 1732.5MHz 23.87 23.22 23.93 22.61	20300 1745.0MHz 24.02 23.67 23.75 22.60
LTE Band			1 1 1 50 50	0 49 99 0 24	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64
LTE Band			1 1 1 50 50 50	0 49 99 0 24 49	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87
LTE Band		QPSK	1 1 1 50 50 50 50	0 49 99 0 24 49	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64
LTE Band		QPSK	1 1 50 50 50 100 enna Gain(dE	0 49 99 0 24 49 0	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87
LTE Band		QPSK  Ante	1 1 1 50 50 50 100 enna Gain(dE	0 49 99 0 24 49 0	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87
LTE Band		QPSK  Ante	1 1 50 50 50 100 enna Gain(dE	0 49 99 0 24 49 0 8i):	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante	1 1 50 50 50 100 enna Gain(dE x. EIRP (dBm P Limit (dBm	0 49 99 0 24 49 0 8i):	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante	1 1 1 50 50 50 100 enna Gain(dE	0 49 99 0 24 49 0 8i):	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante  Max  EIR	1 1 50 50 50 100 enna Gain(dE c. EIRP (dBm P Limit (dBm 1 1	0 49 99 0 24 49 0 8i): n): n):	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante	1 1 50 50 50 100 enna Gain(dE c. EIRP (dBm 1 1 1 1 50	0 49 99 0 24 49 0 8i): n): n): 99	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante  Max  EIR	1 1 50 50 50 100 enna Gain(dE c. EIRP (dBm P Limit (dBm 1 1 1 50 50	0 49 99 0 24 49 0 8i): n): n): 0 49 99 0	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante  Max  EIR	1 1 50 50 50 100 enna Gain(dE c. EIRP (dBm P Limit (dBm 1 1 1 50 50	0 49 99 0 24 49 0 8i): n): n): 0 49 99 0 24 49	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante  Max  EIR  16QAM	1 1 50 50 50 100 enna Gain(dE c. EIRP (dBn P Limit (dBn 1 1 1 50 50 50	0 49 99 0 24 49 0 8i): n): n): 0 49 99 0 24 49	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55 23.41 /	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	QPSK  Ante  Max EIR  16QAM	1 1 50 50 50 100 enna Gain(dE c. EIRP (dBm 1 1 1 1 50 50 50 100 enna Gain(dE	0 49 99 0 24 49 0 8i): n): n): 0 49 99 0 24 49 0	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55 23.41 /	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
	(MHz)	Ante Max Ante Max Ante Max	1 1 50 50 50 100 enna Gain(dE c. EIRP (dBm 1 1 1 1 50 50 50 100 enna Gain(dE c. EIRP (dBm	0 49 99 0 24 49 0 8i): n): 0 49 99 0 24 49 0	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55 23.41 / / / / / / / / / / / / /	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76
4	(MHz)	Ante Max Ante Max Ante Max	1 1 50 50 50 100 enna Gain(dEx. EIRP (dBm 1 1 1 50 50 50 100 enna Gain(dEx. EIRP (dBm P Limit (dBm 1 1 1 50 50 100 enna Gain(dEx. EIRP (dBm	0 49 99 0 24 49 0 8i): n): 0 49 99 0 24 49 0 8i): n):	20050 1720.0MHz 24.17 23.27 23.75 22.73 22.54 22.63 22.72	20175 1732.5MHz 23.87 23.22 23.93 22.61 22.30 22.44 22.59 1.93 26.10 30.00 23.39 22.55 23.41 /	20300 1745.0MHz 24.02 23.67 23.75 22.60 22.64 22.87 22.76



	Bandwidth				Ave	rage Power (dl	3m)
LTE Band	(MHz)	Modulation	RB Size	RB Offset	23205	23230	23255
	(IVITZ)				779.5MHz	782.0MHz	784.5MHz
			1	0	23.30	23.26	23.36
			1	12	23.31	23.42	23.40
			1	24	23.35	23.25	23.75
		QPSK	12	0	22.42	22.26	22.30
			12	6	22.35	22.39	22.36
			12	11	22.33	22.40	22.70
			25	0	22.35	22.35	22.31
		Antenna Gain(dBi):				1.03	
		Max. ERP (dBm):			22.63		
13	5	ERP Limit (dBm):			34.77		
13	5	16QAM	1	0	22.86	22.81	22.83
			1	12	22.87	22.77	22.73
			1	24	22.55	22.82	23.06
			12	0	21.36	21.26	21.25
			12	6	21.31	21.41	21.25
			12	11	21.34	21.57	21.71
			25	0	21.43	21.50	21.25
		Ante	nna Gain(dE	Bi):	1.03		
			x. ERP (dBm		21.94		
			P Limit (dBm			34.77	
	Pondwidth				Ave	rage Power (dl	3m)

	Dana da dala				Ave	erage Power (dE	Bm)
LTE Band	Bandwidth (MHz)	Modulation	RB Size	RB Offset		23230	•
	(1011 12)					782.0MHz	
			1	0	/	22.88	/
			1	24	/	23.50	/
			1	49	/	22.72	/
		QPSK	25	0	/	22.36	/
			25	12	/	22.40	/
			25	24	/	22.83	/
			50	0	/	22.12	/
		Antenna Gain(dBi):			1.03		
		Max. ERP (dBm):			22.38		
13	10	ERI	P Limit (dBm	):	34.77		
10	10		1	0	/	22.67	/
			1	24	/	22.82	/
			1	49	/	23.17	/
		16QAM	25	0	/	22.41	/
			25	12	/	22.63	/
			25	24	/	22.47	/
			50	0	/	/	1
			enna Gain(dB			1.03	
			x. ERP (dBm	,		22.05	
		ERI	P Limit (dBm	):		34.77	<u> </u>

Note: EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi). ERP (dBm) = EIRP (dBm) - 2.15 (dB).



## 6.2 Peak-to-Average Ratio

Test Requirement:	Part 27.50(d)(5)
Limit:	The peak-to-average ratio (PAR) of the transmission may not exceed 13 dB.
Test Setup:	System simulator  Splitter ATT EUT  Spectrum Analyzer
Test Procedure:	<ol> <li>The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation.</li> <li>Set the CCDF option in spectrum analyzer, RBW ≥ OBW,</li> <li>Set the EUT working in highest power level, measured and recorded the 0.1% as PAPR level.</li> <li>Repeat step 1~3 at other frequency and modulations.</li> </ol>
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed

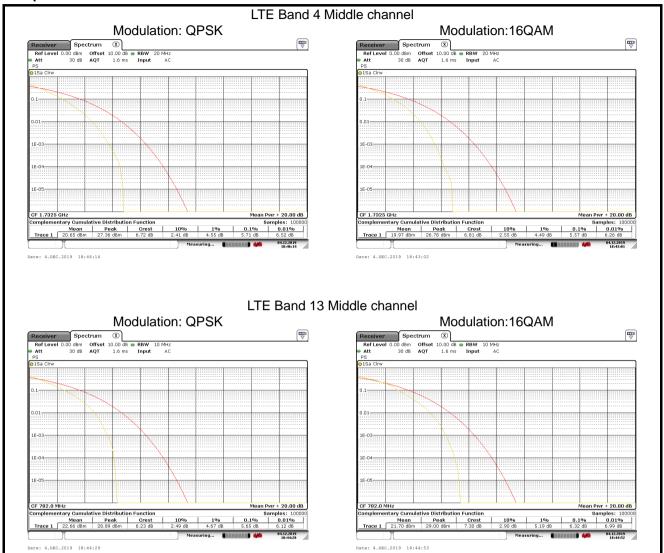


#### **Measurement Data (Worst case):**

Bandwidth	Modulation	RB Size	RB Offset	PAPR				
	LTE Band 4 (Middle Channel)							
OOM! I-	QPSK	100	0	5.71				
20MHz	16QAM	27	0	5.57				
	LTE Band 13 (Middle Channel)							
10ML-	QPSK	50	0	5.65				
10MHz	16QAM	27	0	6.32				



#### Test plots as below:





## 6.3 Occupy Bandwidth

Test Requirement:	Part 27.53(h), Part 27.53(c)
Test Setup:	System simulator Splitter ATT EUT Spectrum Analyzer
Test Procedure:	<ol> <li>The EUT's output RF connector was connected with a short cable to the spectrum analyzer</li> <li>RBW was set to about 1% ~ 5% of emission BW, VBW= 3 times RBW.</li> <li>-26dBc display line was placed on the screen (or 99% bandwidth), the occupied bandwidth is the delta frequency between the two points where the display line intersects the signal trace.</li> </ol>
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed



#### **Measurement Data:**

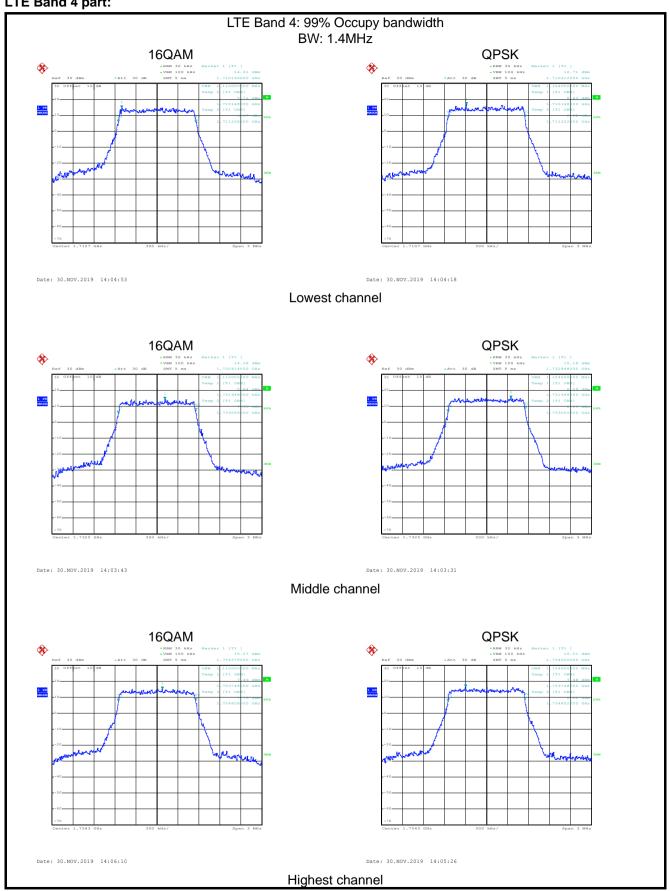
		LTI	E Band 4		
Bandwidth	Channel	Frequency(MHz)	Modulation	99% OBW (kHz)	-26dBcEBW (kHz)
	40057	4740.7	16QAM	1110	1338
	19957	1710.7	QPSK	1104	1374
4 41411-	ALI- 2047E	4700 5	16QAM	1110	1368
1.4MHz	20175	1732.5	QPSK	1104	1392
	20202	1754.3	16QAM	1110	1356
	20393	1754.5	QPSK	1104	1368
	40005	4744.5	16QAM	2748	3120
	19965	1711.5	QPSK	2748	3168
OMI I-	20475	4700.5	16QAM	2748	3144
3MHz	20175	1732.5	QPSK	2760	3132
	20205	1750 F	16QAM	2736	3156
	20385	1750.5	QPSK	2748	3144
	40075	4740.5	16QAM	4560	5820
	19975	1712.5	QPSK	4560	5780
5MHz	20175	1732.5	16QAM	4560	5760
SIVITZ	20175	1732.5	QPSK	4560	5900
	20375	1750 F	16QAM	4580	5720
	20375	1752.5	QPSK	4560	5640
	20000	1715.0	16QAM	/	/
	20000	1715.0	QPSK	9320	11840
10MHz	20175	1732.5	16QAM	/	/
TOIVII 12	20175	1732.5	QPSK	9240	11640
	20350	1750.0	16QAM	/	/
	20330	1730.0	QPSK	9320	11800
	20025	1717.5	16QAM	/	/
	20025	1717.5	QPSK	13680	16620
15MHz	20175	1732.5	16QAM	/	/
13101112	20173	1732.3	QPSK	13680	16440
	20325	1747.5	16QAM	/	/
	20323	1747.5	QPSK	13620	16320
	20050	1720.0	16QAM	/	/
	20030	1720.0	QPSK	18160	20800
20MHz	20175	1732.5	16QAM	/	/
ZUIVII IZ	20175	1732.0	QPSK	18160	20720
	20300	1745.0	16QAM	/	/
	20000	17-40.0	QPSK	18080	20720



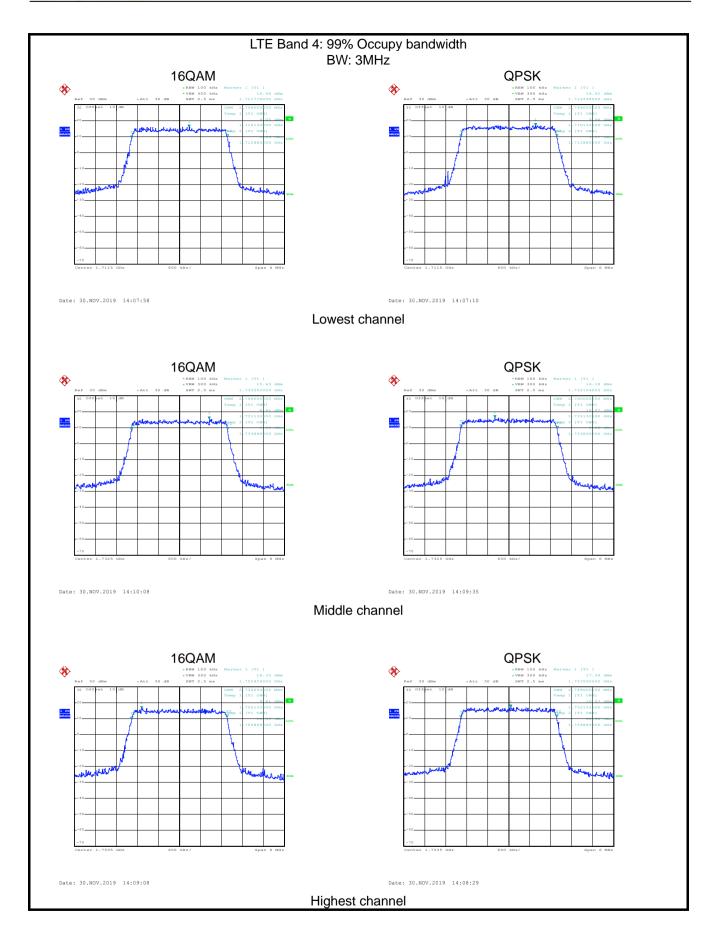
LTE Band 13							
Bandwidth	Channel	Frequency(MHz)	Modulation	99% OBW (kHz)	-26dBcEBW (kHz)		
	23205	779.5	16QAM	4580	5500		
	23205	119.5	QPSK	4580	5700		
ENALI-	5MHz 23230	782.0	16QAM	4580	5820		
SIVIFIZ			QPSK	4580	5860		
	23255		16QAM	4520	5740		
	23233	784.5	QPSK	4560	5680		
10MH=	22220	700.0	16QAM	/	/		
10MHz	23230	782.0	QPSK	9440	11960		



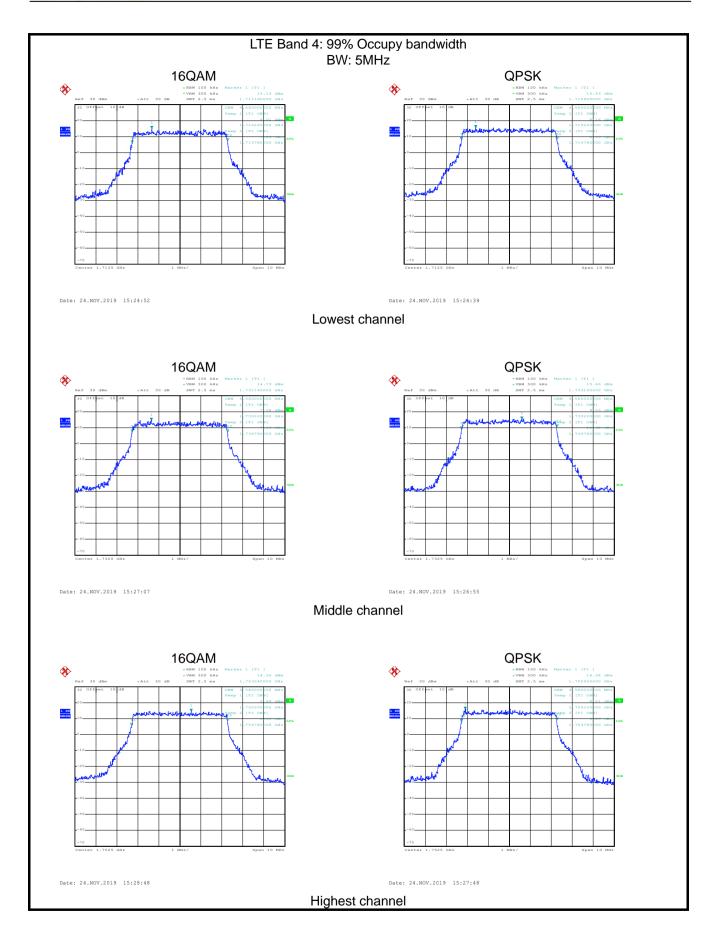
# Test plot as follows: LTE Band 4 part:



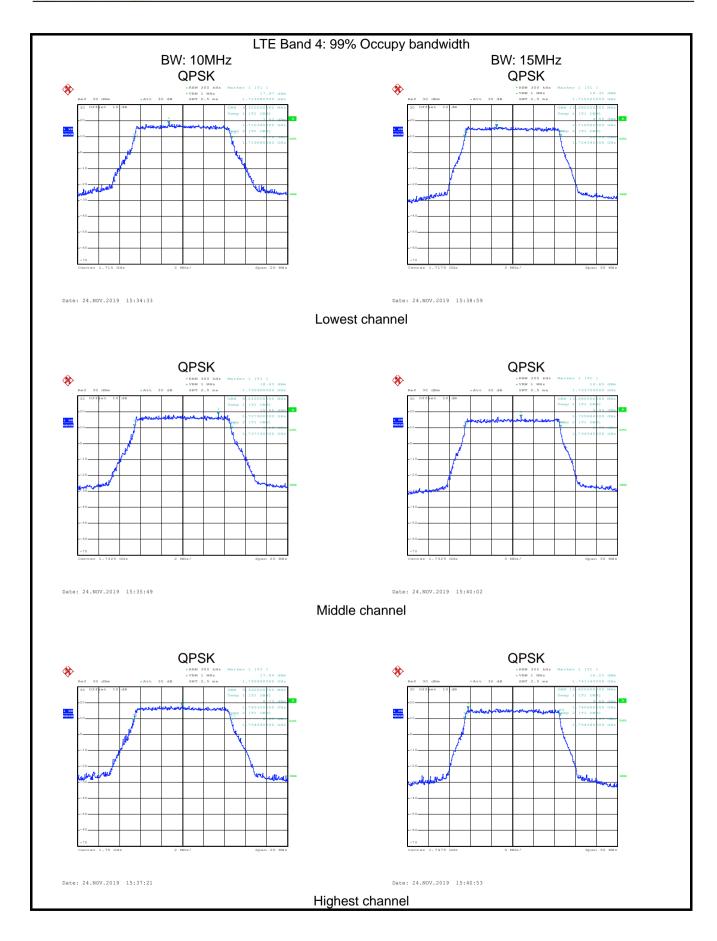




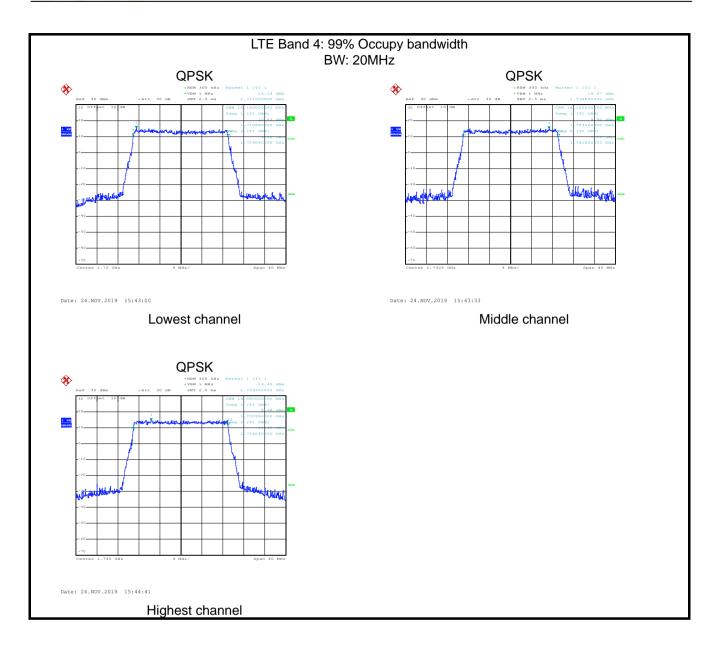




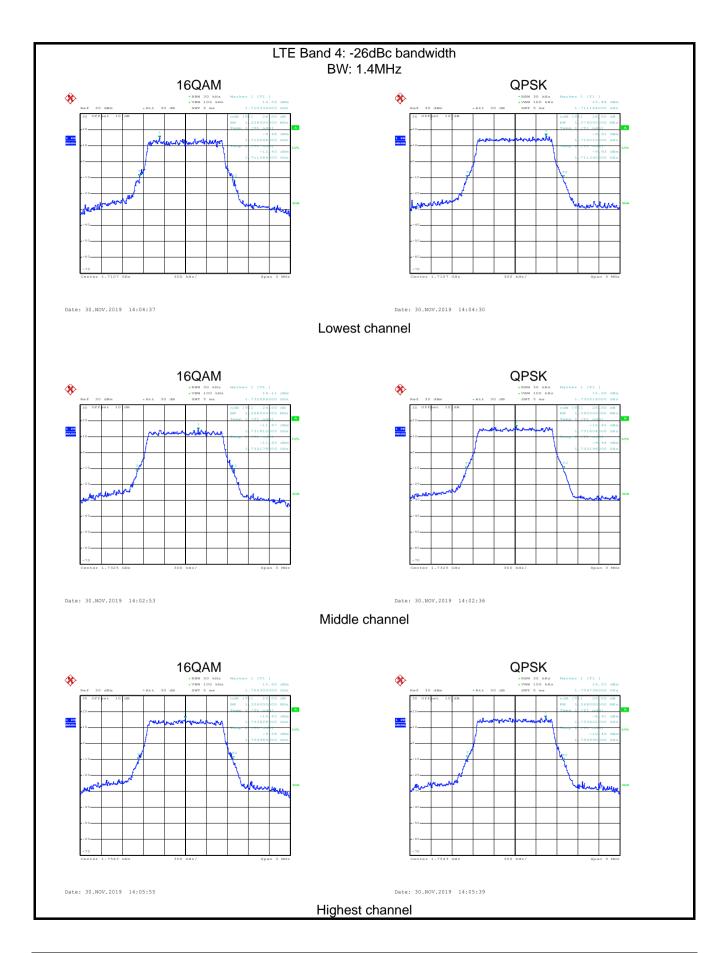




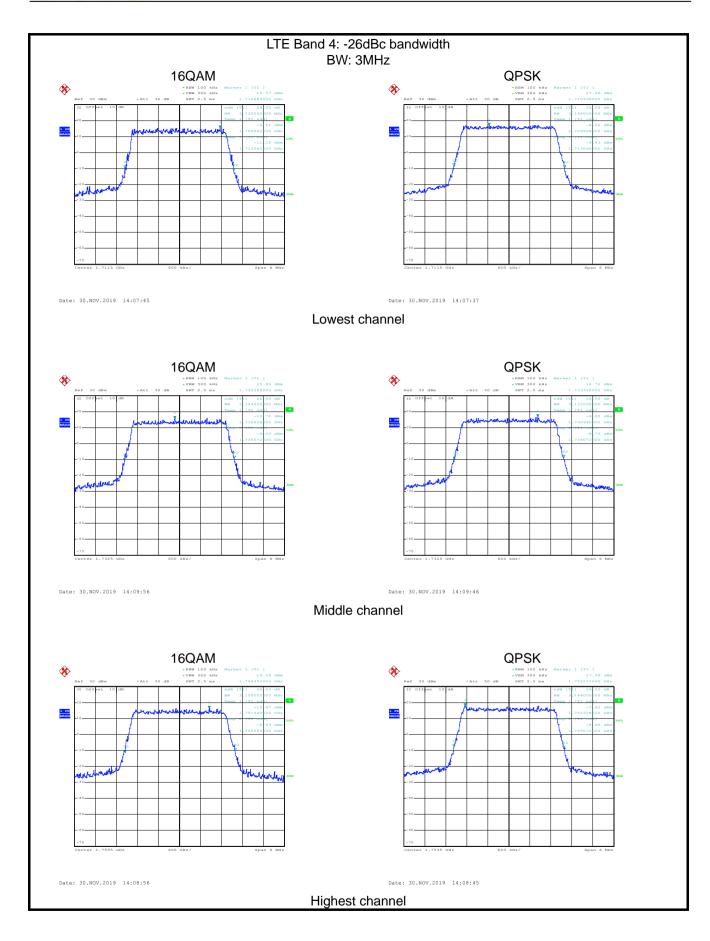




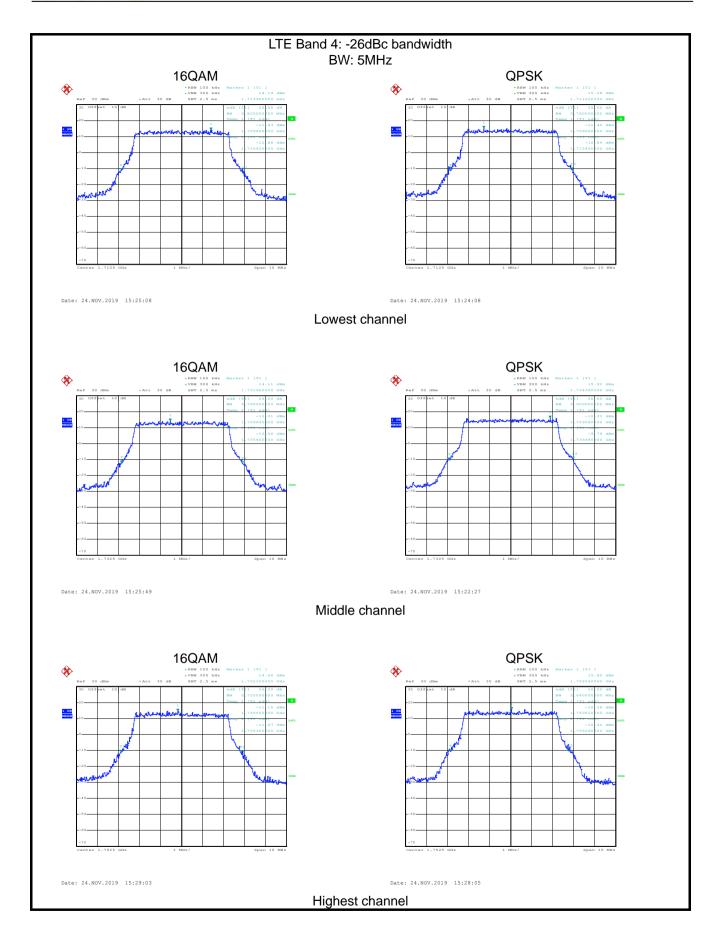




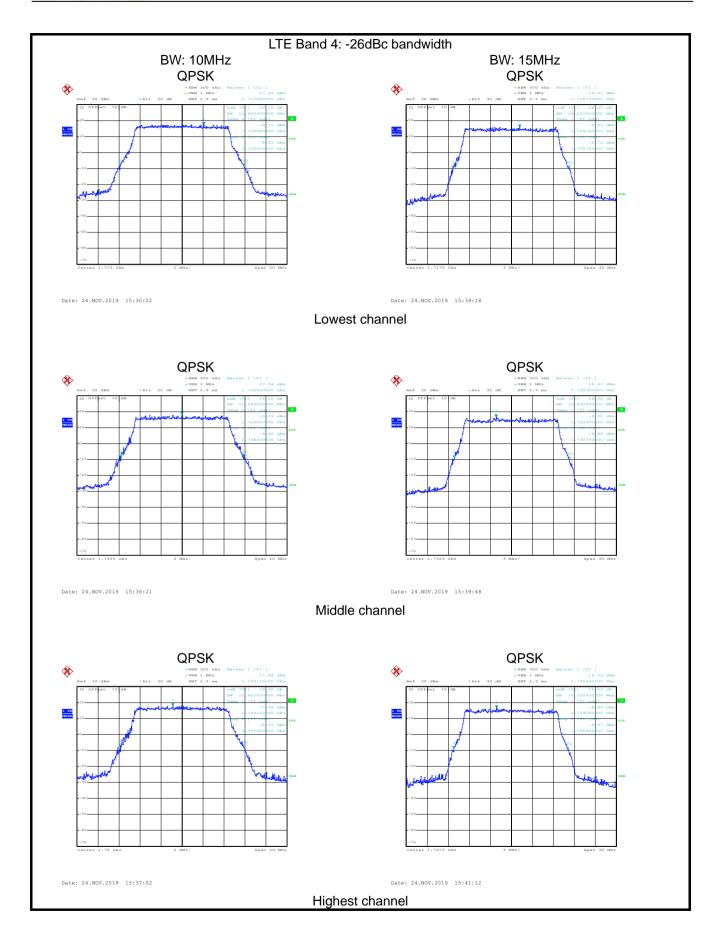




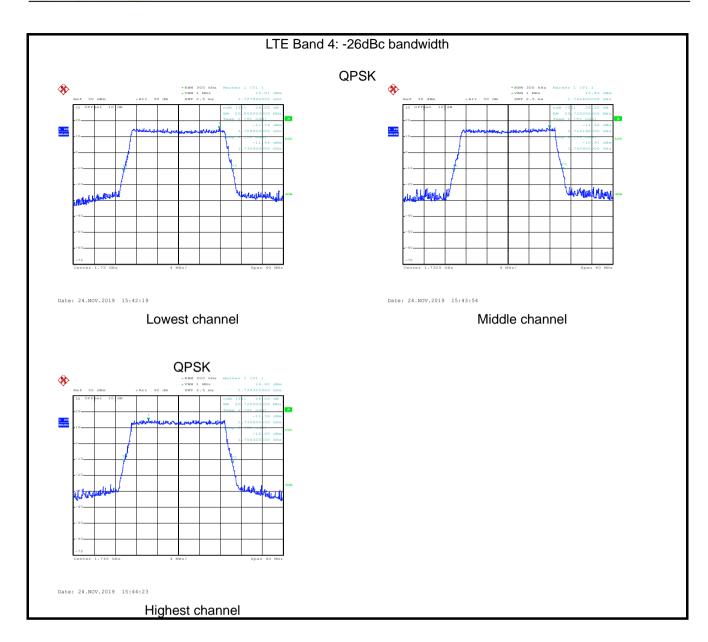






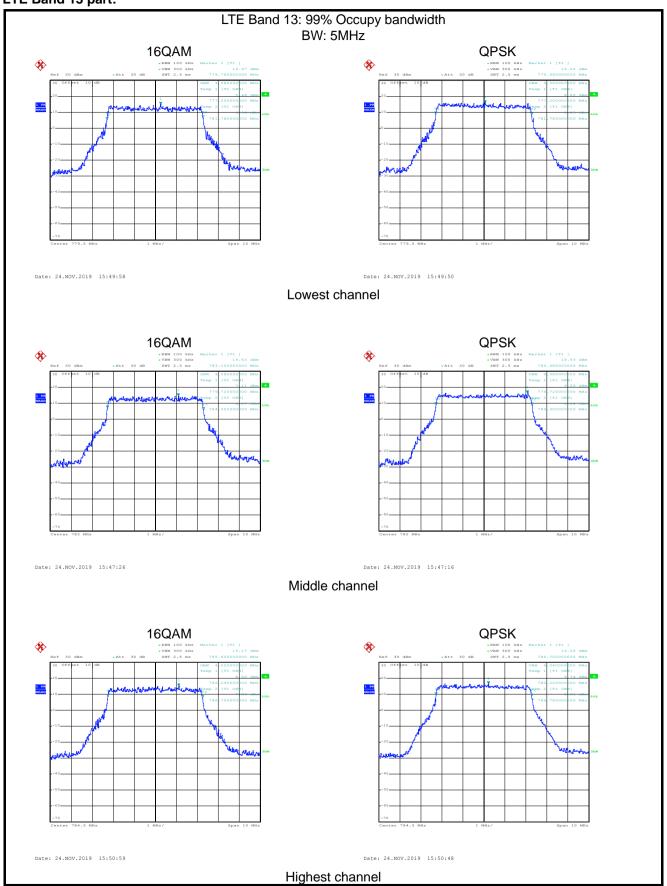




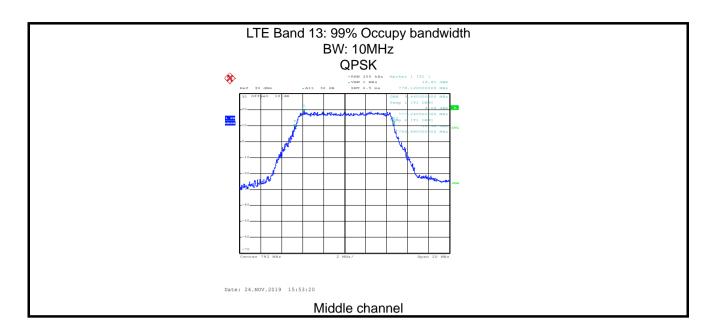




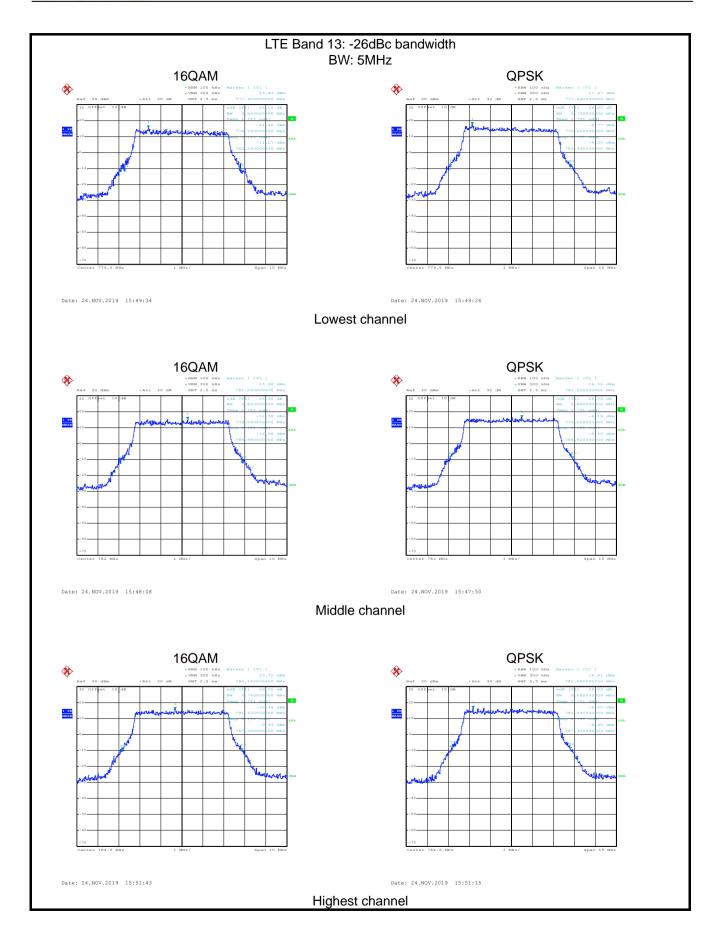
#### LTE Band 13 part:



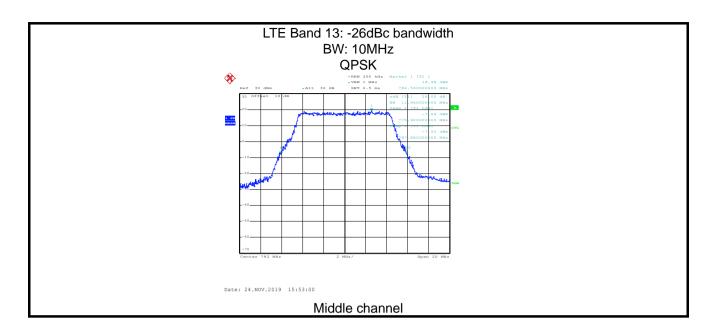












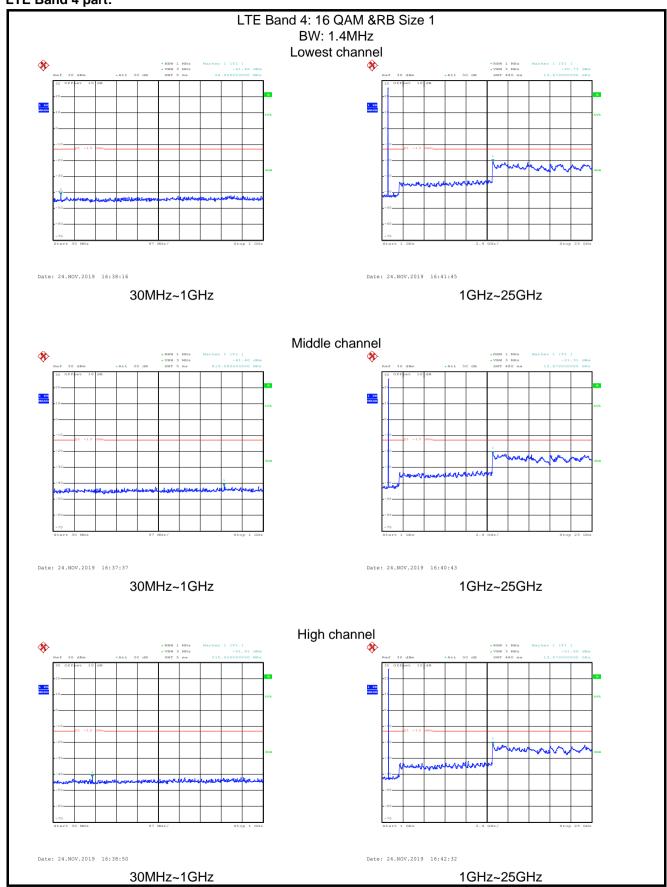


## **6.4** Out of band emission at antenna terminals

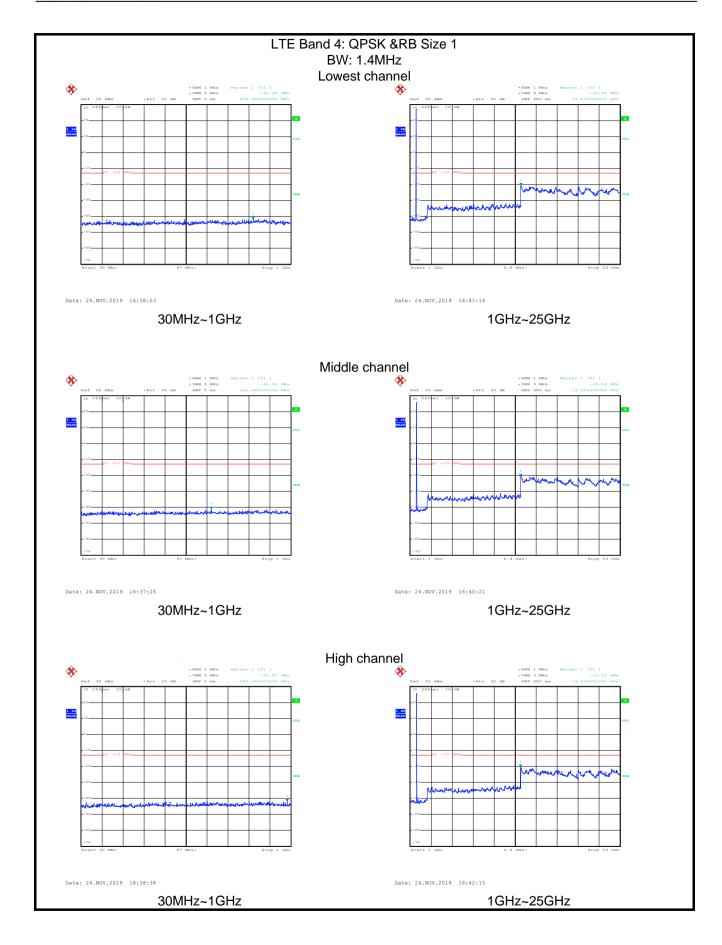
Test Requirement:	part 27.53(h), Part 27.53(c)
Limit:	LTE Band4: Thepower of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 log <sub>10</sub> (P) dB (-13 dBm). LTE Band13: The power of any emission shall be attenuated outside the band below the transmitter power (P) by at least 43 + 10 log (P) dB(-13 dBm). For operations in the 746-758 MHz, 775-788 MHz, and 805-806 MHz bands, emissions in the band 1559-1610 MHz shall be limited to -70 dBW/MHz equivalent isotropically radiated power (EIRP) for wideband signals.
Test Setup:	System simulator  Splitter ATT EUT  Spectrum Analyzer
Test Procedure:	<ol> <li>The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation.</li> <li>The resolution bandwidth of the spectrum analyzer was set at 100 kHz when below 1GHz, 1MHz when above 1 GHz; sufficient scans were taken to show the out of band Emissions if any up to 10th harmonic.</li> <li>For the out of band: Set the RBW=100 kHz, VBW=300 kHz when below 1 GHz, RBW =1 MHz, VBW=3 MHz when above 1 GHz, Start=30MHz, Stop= 10th harmonic.</li> <li>Band Edge Requirements: In the 1 MHz bands immediately outside and adjacent to the frequency block, a resolution bandwidth of at least 1 percent of the emission bandwidth of the fundamental emission of the transmitter may be employed to measure the out of band Emissions.</li> </ol>
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed
Remark:	Pre-scan all RB Size and offset, and found the RB Size and offset of worst case, so the report shows only the worst case test data.



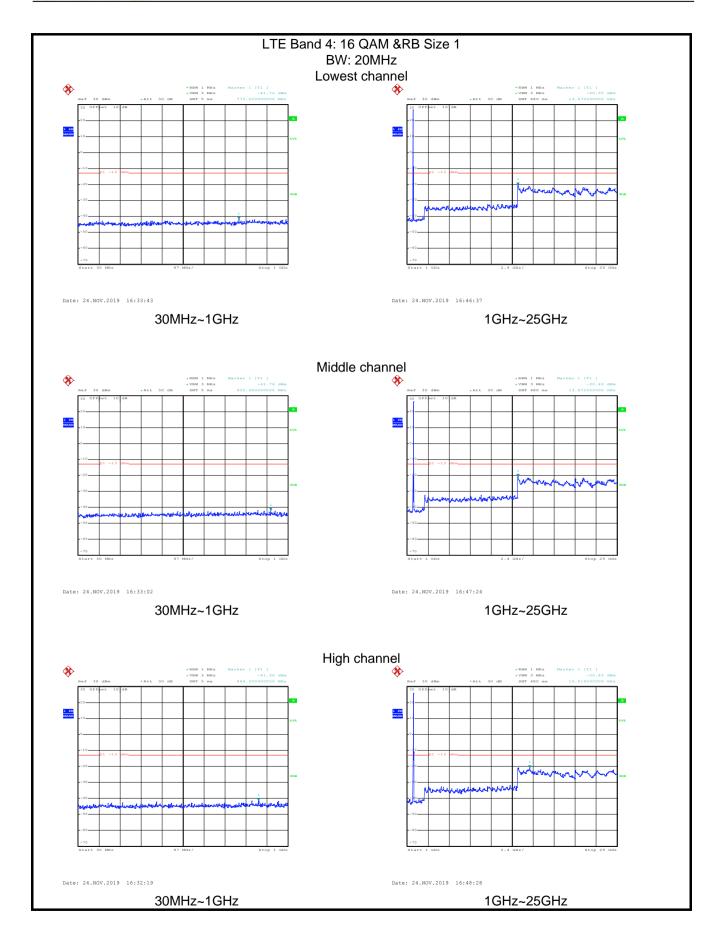
# Test plots as follows (Conducted spurious emission) (worst case): LTE Band 4 part:



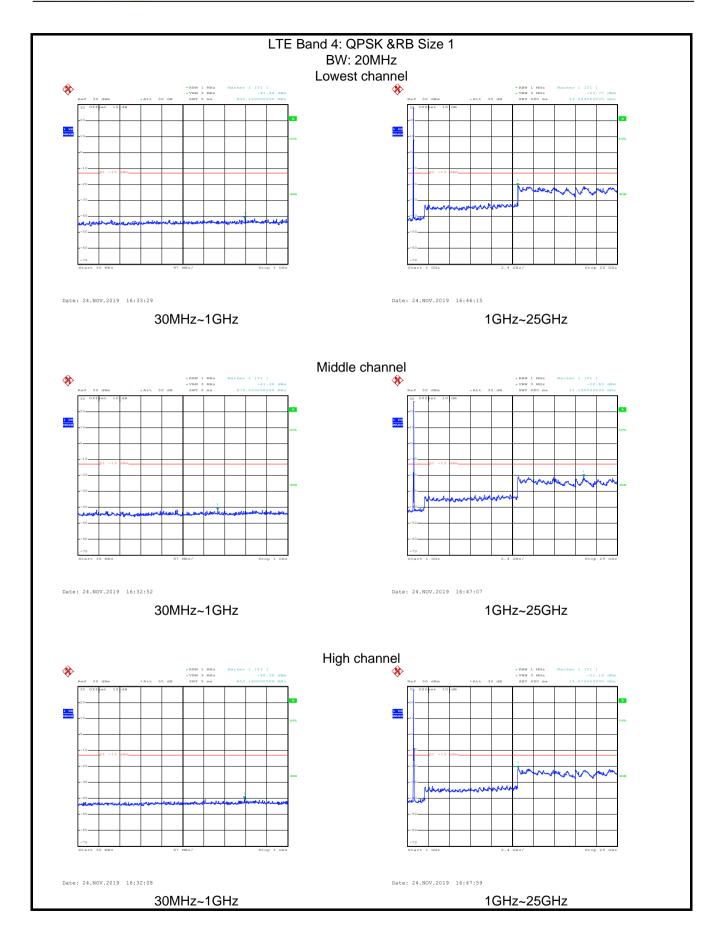




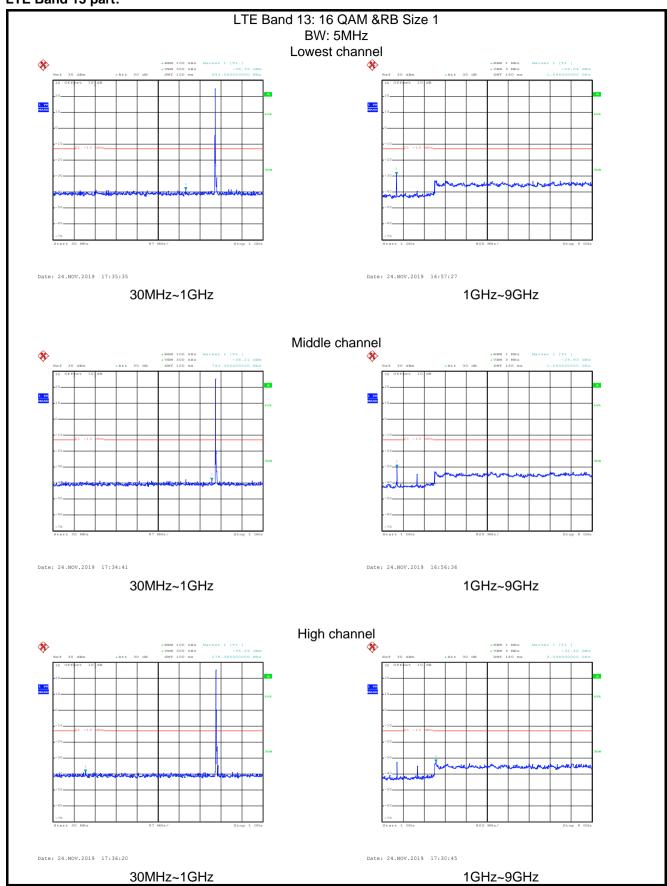




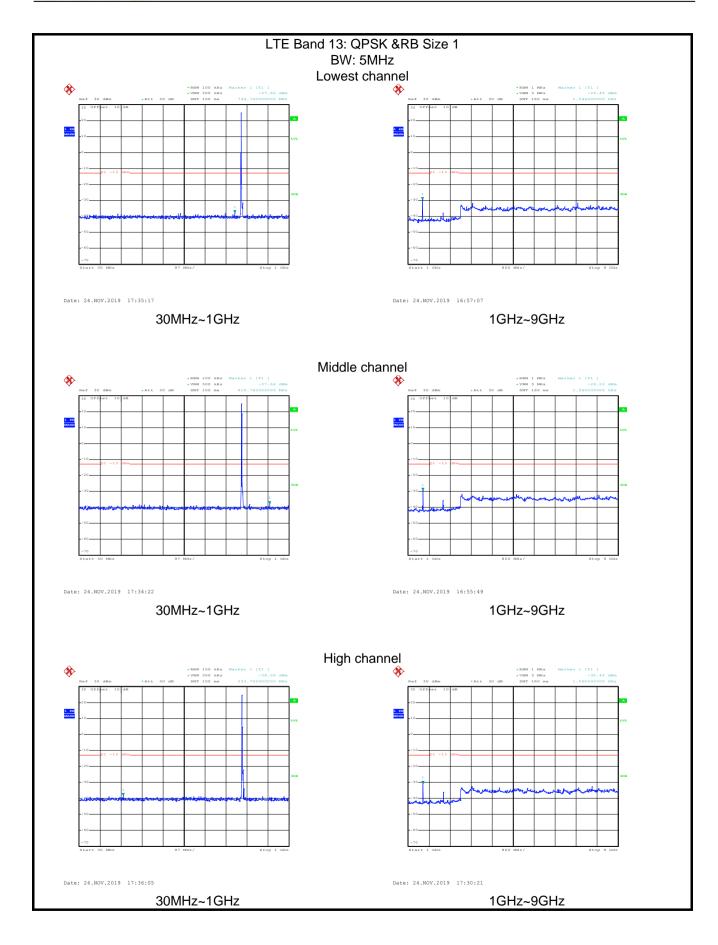




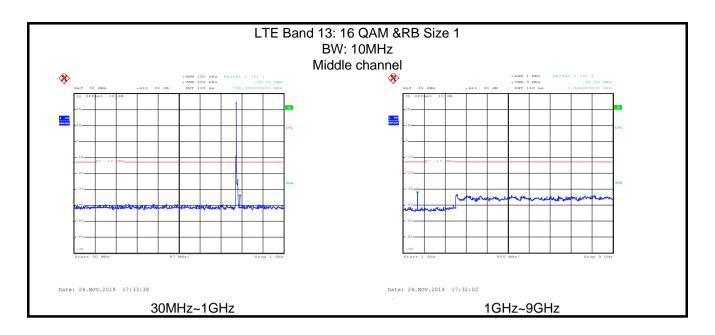




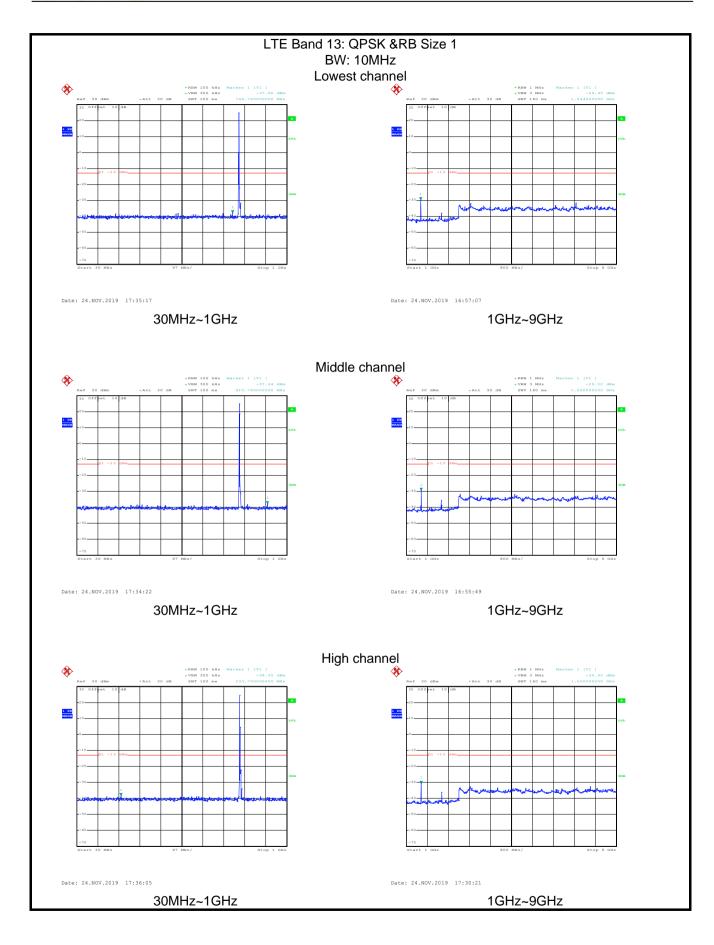






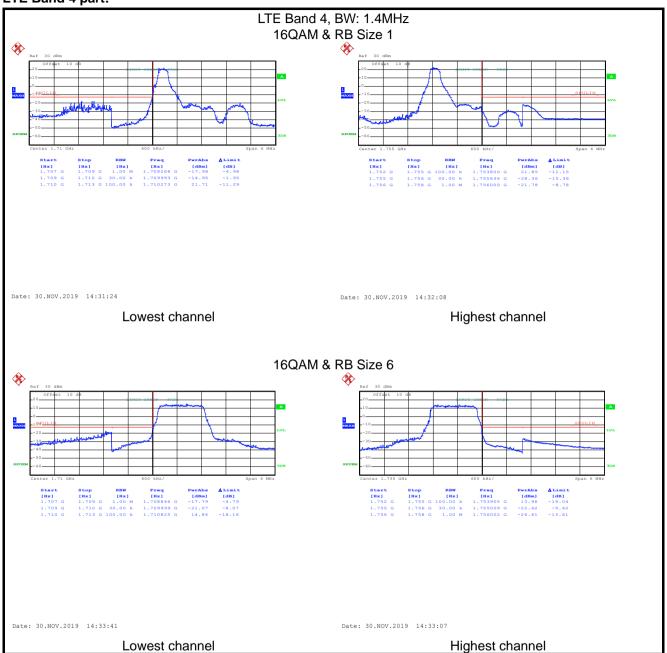




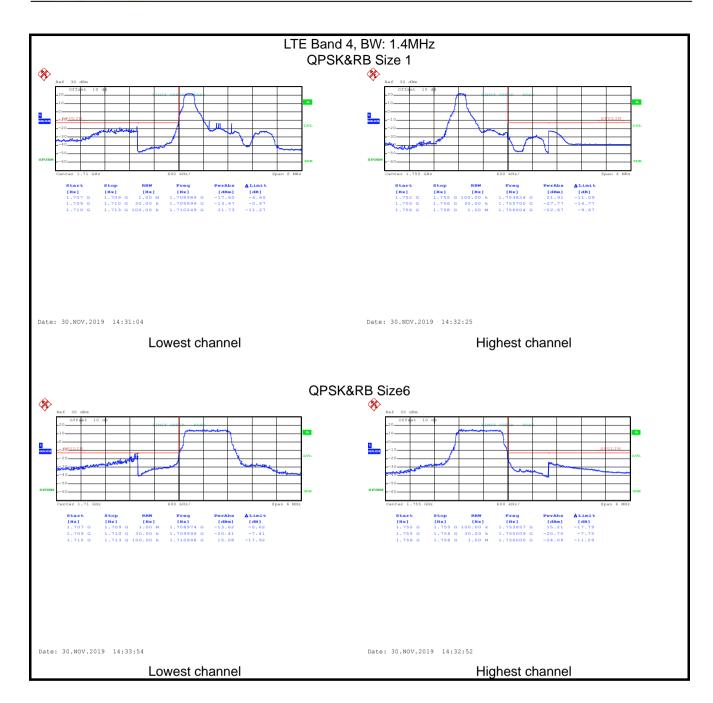




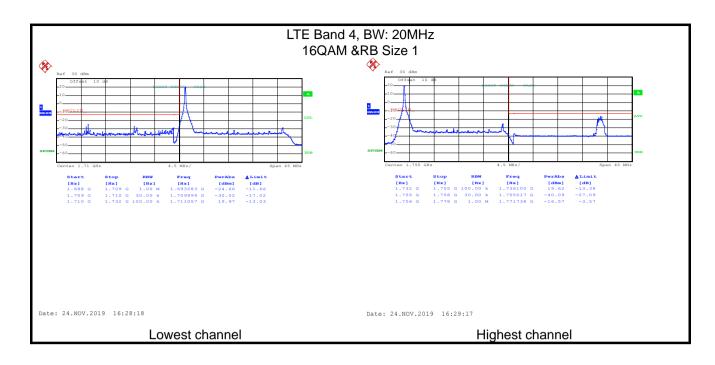
## **Band edge emission:**



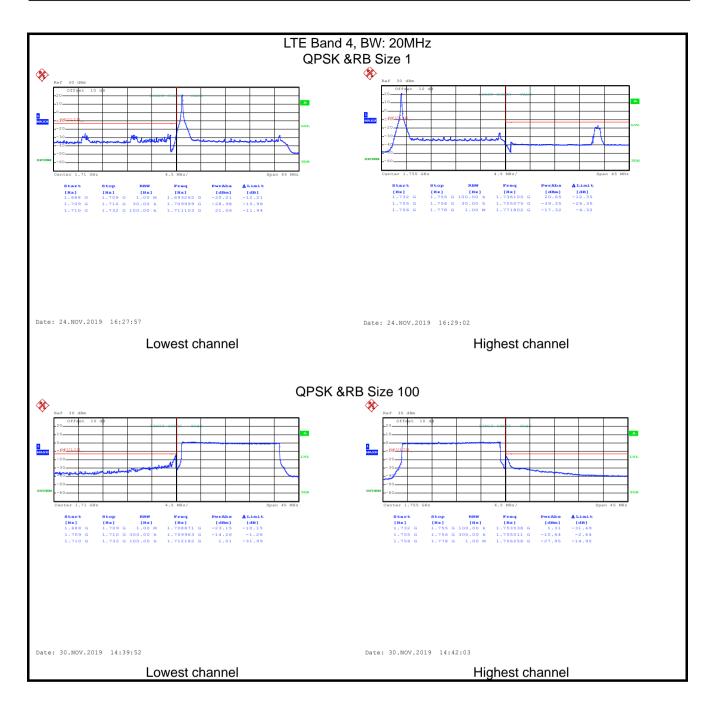




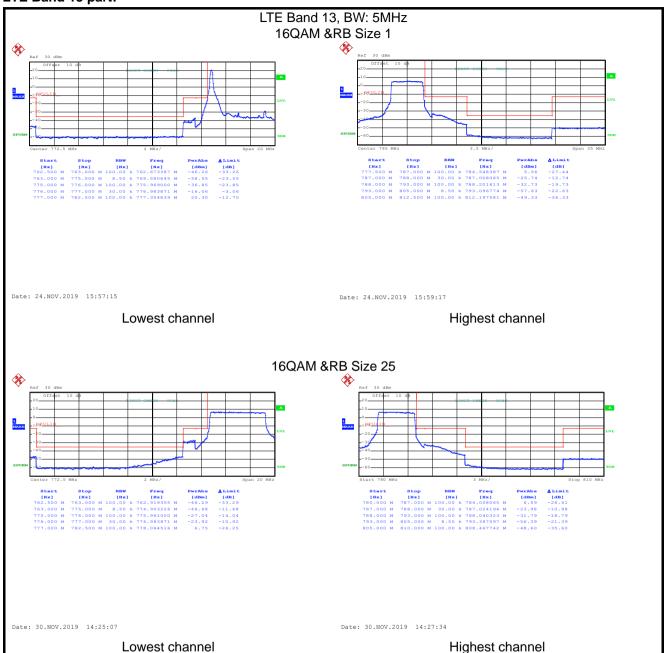




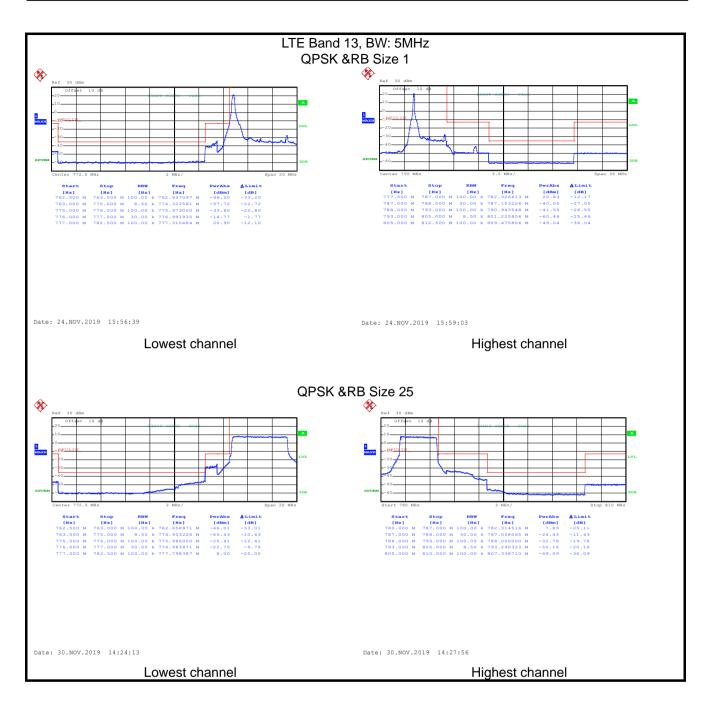




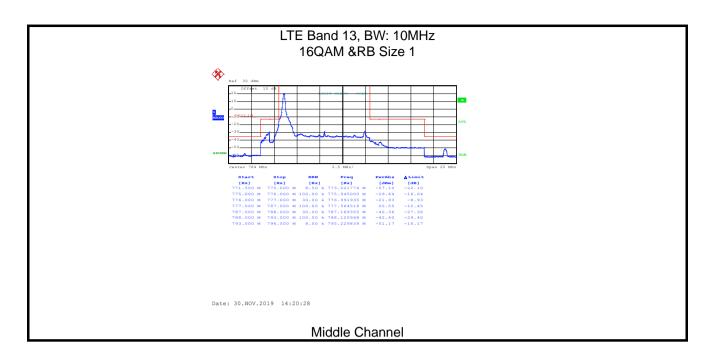




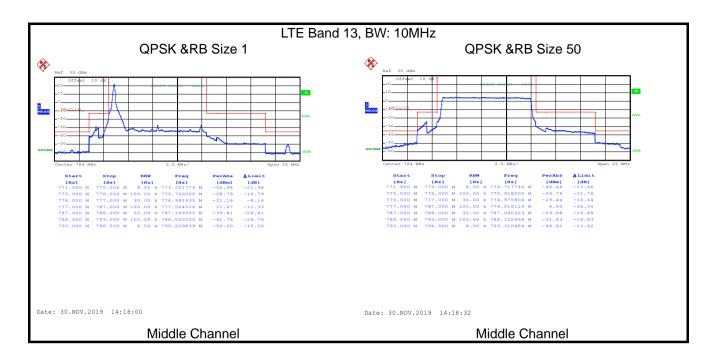














## 6.5 Field strength of spurious radiation measurement

6.5 Field strength of spi	urious radiation measurement
Test Requirement:	Part 27.53(h), Part 27.53(c)(f)
Limit:	LTE Band4: Thepower of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 log <sub>10</sub> (P) dB (-13 dBm). LTE Band13: The power of any emission shall be attenuated outside the band below the transmitter power (P) by at least 43 + 10 log (P) dB(-13 dBm). For operations in the 746-758 MHz, 775-788 MHz, and 805-806 MHz bands, emissions in the band 1559-1610 MHz shall be limited to -70 dBW/MHz equivalent isotropically radiated power (EIRP) for wideband signals.
Test setup:	Below 1GHz
	Antenna Tower  Ground Reference Plane Generator Monitor Power Amplifier Amplifier
	Horn Antenna Tower  AE EUT  Horn Antenna Tower  Ground Reference Plane  Test Receiver  Anguler  Controller
Test Procedure:	1. The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental
	frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.  2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations.  3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method.  4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency.



	ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB)
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details.
Test results:	Passed

#### **Measurement Data:**

## LTE Band 4 part:

	l	TE Band 4, WB: 1.4MH	z		
		RB size 1 & RB offset (	)		
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result	
Frequency (IVII 12)	Polarization	Level (dBm)	Limit (ubm)	Result	
		Lowest Channel			
3421.40	Vertical	-40.46			
5132.10	V	-45.72			
6842.80	V	-39.89	-13.00	Pass	
3421.40	Horizontal	-42.44	-13.00	P 455	
5132.10	Н	-45.90			
6842.80	Н	-40.23			
		Middle Channel			
3465.00	Vertical	-40.81			
5197.50	V	-45.59			
6930.00	V	-40.16	-13.00	Dana	
3465.00	Horizontal	-42.78	-13.00	Pass	
5197.50	Н	-45.88			
6930.00	Н	-39.84			
		Highest Channel			
3508.60	Vertical	-40.11			
5262.90	V	-45.63			
7017.20	V	-39.58	42.00	Dage	
3508.60	Horizontal	-42.31	-13.00	Pass	
5262.90	Н	-45.46			
7017.20	Н	-40.51			

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



		LTE Band 4, WB: 3MH	Z				
		RB size 1 & RB offset	0				
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result			
riequency (MHZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Result			
	Lowest Channel						
3423.00	Vertical	-41.12					
5134.50	V	-45.97					
6846.00	V	-39.69	-13.00	Pass			
3423.00	Horizontal	-43.10		Pass			
5134.50	Н	-46.35					
6846.00	Н	-39.41					
		Middle Channel					
3465.00	Vertical	-39.64					
5197.50	V	-46.06					
6930.00	V	-39.32	-13.00	Pass			
3465.00	Horizontal	-41.99	-13.00	Pa55			
5197.50	Н	-45.57					
6930.00	Н	-40.87					
		Highest Channel					
3507.00	Vertical	-40.92					
5260.50	V	-45.26					
7014.00	V	-40.51	-13.00	Pass			
3507.00	Horizontal	-43.01	-13.00	Pass			
5260.50	Н	-45.65					
7014.00	Н	-40.20					

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



		LTE Band 4, WB: 5MH	Z	
		RB size 1 & RB offset	0	
Frequency (MHz)	Spurious Emission		Limit (dPm)	Result
r requericy (Wir 12)	Polarization	Level (dBm)	Limit (dBm)	Result
		<b>Lowest Channel</b>		
3425.00	Vertical	-40.13		
5137.50	V	-45.61		
6850.00	V	-39.45	-13.00	Pass
3425.00	Horizontal	-42.04	-13.00	Fd55
5137.50	Н	-45.88		
6850.00	Н	-39.83		
		Middle Channel		
3465.00	Vertical	-40.04		
5197.50	V	-45.54		
6930.00	V	-39.60	-13.00	Pass
3465.00	Horizontal	-42.36	-13.00	F d 5 5
5197.50	Н	-46.18		
6930.00	Н	-39.99		
		<b>Highest Channel</b>		
3505.00	Vertical	-40.34		
5257.50	V	-45.21		
7010.00	V	-39.21	-13.00	Pass
3505.00	Horizontal	-42.39	-13.00 Pass	F d 3 3
5257.50	Н	-45.71		
7010.00	Н	-40.10		

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	ı	LTE Band 4, WB: 10MH	lz		
		RB size 1 & RB offset	0		
Fragues av (MHz)	Spurious Emission		Limit (dDm)	D 14	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
		<b>Lowest Channel</b>			
3430.00	Vertical	-40.82			
5145.00	V	-45.97			
6860.00	V	-39.56	-13.00	Pass	
3430.00	Horizontal	-42.33	-13.00	F d 5 5	
5145.00	Н	-45.76			
6860.00	П	-40.40			
		Middle Channel			
3465.00	Vertical	-41.01			
5197.50	V	-46.20			
6930.00	V	-39.55	12.00	Door	
3465.00	Horizontal	-42.81	-13.00	Pass	
5197.50	Н	-45.76			
6930.00	Н	-40.19			
		Highest Channel			
3500.00	Vertical	-41.48			
5250.00	V	-46.64			
7000.00	V	-39.91	-13.00	Pass	
3500.00	Horizontal	-42.81	-13.00	Pass	
5250.00	Н	-45.33			
7000.00	Н	-40.64			

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	ı	LTE Band 4, WB: 15MH	lz	
		RB size 1 & RB offset	0	
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result
riequency (IVII 12)	Polarization	Level (dBm)	Limit (dbin)	Result
		Lowest Channel		
3435.00	Vertical	-40.29		
5152.50	V	-45.80		
6870.00	V	-39.47	-13.00	Pass
3435.00	Horizontal	-42.48		F455
5152.50	Н	-45.65		
6870.00	Н	-40.70		
		Middle Channel		
3465.00	Vertical	-39.94		
5197.50	V	-45.96		
6930.00	V	-39.65	-13.00	Pass
3465.00	Horizontal	-42.67	-13.00	Fd55
5197.50	Н	-45.55		
6930.00	Н	-40.95		
		<b>Highest Channel</b>		
3495.00	Vertical	-40.10		
5242.50	V	-44.74		
6990.00	V	-39.59	-13.00	Pass
3495.00	Horizontal	-42.46	-13.00	Fd55
5242.50	Н	-45.55		
6990.00	Н	-39.83		

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	ı	LTE Band 4, WB: 20MI	Hz	
		RB size 1 & RB offset	0	
	Spuriou	s Emission	Limit (dPm)	Desult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		<b>Lowest Channel</b>		
3440.00	Vertical	-39.98		
5160.00	V	-46.28		
6880.00	V	-39.24	-13.00	Pass
3440.00	Horizontal	-42.61	-13.00	Fd55
5160.00	Н	-45.44		
6880.00	Н	-41.06		
		Middle Channel		
3465.00	Vertical	-40.50		
5197.50	V	-46.46		
6930.00	V	-39.07	-13.00	Pass
3465.00	Horizontal	-42.03	-13.00	Pass
5197.50	Н	-45.77		
6930.00	Н	-40.90		
		Highest Channel		
3490.00	Vertical	-40.74		
5235.00	V	-46.73		
6980.00	V	-39.17	-13.00	Pass
3490.00	Horizontal	-42.39	-13.00	Pass
5235.00	Н	-45.44		
6980.00	Н	-41.35		

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



		LTE Band 13, WB: 5MF	łz	
		RB size 1 & RB offset	0	
Fraguenov (MHz)	Spuriou	s Emission	Limit (dPm)	Decult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		<b>Lowest Channel</b>		
1559.00	Vertical	-41.92		
2338.50	V	-46.88		
3118.00	V	-52.58	-13.00	Pass
1559.00	Horizontal	-40.09	-13.00	Fd55
2338.50	Н	-51.84		
3118.00	Н	-51.79		
		Middle Channel		
1564.00	Vertical	-41.64		
2346.00	V	-46.40		
3128.00	V	-52.35	-13.00	Pass
1564.00	Horizontal	-39.83	-13.00	F d 5 5
2346.00	Н	-51.75		
3128.00	Н	-52.15		
		Highest Channel		
1569.00	Vertical	-41.42		
2353.50	V	-45.94		
3138.00	V	-52.63	12.00	Door
1569.00	Horizontal	-39.76	-13.00 Pass	Pass
2353.50	Н	-52.02		
3138.00	Н	-51.99		

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	L	TE Band 13, WB: 10M	Hz	
		RB size 1 & RB offset	0	
Fraguency (MHz)	Spuriou	s Emission	Limit (dPm)	Decult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		<b>Lowest Channel</b>		
1564.00	Vertical	-41.61		
2346.00	V	-47.30		
3128.00	V	-52.21	-13.00	Pass
1564.00	Horizontal	-40.25	-13.00	Fd55
2346.00	Н	-52.17		
3128.00	Н	-51.94		
		Middle Channel		
1564.00	Vertical	-41.80		
2346.00	V	-47.08		
3128.00	V	-52.47	-13.00	Pass
1564.00	Horizontal	-40.64	-13.00	Fd55
2346.00	Н	-51.80		
3128.00	Н	-51.67		
		Highest Channel		
1564.00	Vertical	-42.27		
2346.00	V	-47.25		
3128.00	V	-52.12	-13.00	Pass
1564.00	Horizontal	-40.86	-13.00	Pass
2346.00	Н	-51.48		
3128.00	Н	-51.42		

<sup>1.</sup> The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

<sup>2.</sup> For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



# 6.6 Frequency stability V.S. Temperature measurement

Test Requirement:	Part 27.54, Part 2.1055(a)(1)(b)
Limit:	±2.5ppm
Test setup:	SS  Divider  Temperature & Humidity Chamber  Power Source
Test procedure:	<ol> <li>The equipment under test was connected to an external DC power supply and input rated voltage.</li> <li>RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators.</li> <li>The EUT was placed inside the temperature chamber.</li> <li>Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency.</li> <li>Turn EUT off and set the chamber temperature to -30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency.</li> <li>Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached</li> </ol>
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed



## Measurement Data (worst case):

Reference F	requency: LTE Band 4	(10MHz) Midd	le channel=20175	channel=1732.5	0MHz
Power supplied	Temperature (°C)	Temperature (°C) Frequence		Limit (ppm)	Result
(Vdc)	Temperature (C)	Hz	ppm	Еппі (рріп)	Nesuit
		QPSK			
	-30	178	0.102742		
	-20	164	0.094661		
	-10	158	0.091198		Pass
	0	150	0.086580		
3.80	10	143	0.082540	±2.5	
	20	136	0.078499	-	
	30	129	0.074459		
	40	120	0.069264		
	50	116	0.066955		
		16QAM			
	-30	170	0.098124		
	-20	162	0.093506		
	-10	157	0.090620		
	0	149	0.086003		
3.80	10	140	0.080808	±2.5	Pass
	20	133	0.076768		
	30	126	0.072727		
	40	117	0.067532		
	50	110	0.063492		



Reference F	requency: LTE Band 1	3(10MHz) Mid	dle channel=2323	0 channel=782.0	0MHz
Power supplied (Vdc)	Temperature (°C)	Frequency error		Limit (ppm)	Result
	remperature (c)	Hz	ppm	Limit (ppm)	Kesuit
		QPSK			
3.80	-30	177	0.226343	±2.5	Pass
	-20	161	0.205882		
	-10	153	0.195652		
	0	146	0.186701		
	10	137	0.175192		
	20	130	0.166240		
	30	124	0.158568		
	40	118	0.150895		
	50	109	0.139386		
		16QAM			
3.80	-30	175	0.223785	±2.5	Pass
	-20	160	0.204604		
	-10	152	0.194373		
	0	147	0.187980		
	10	139	0.177749		
	20	130	0.166240		
	30	121	0.154731		
	40	113	0.144501		
	50	108	0.138107		



# 6.7 Frequency stability V.S. Voltage measurement

Test Requirement:	Part 27.54, Part 2.1055(d)(2)
Limit:	±2.5ppm
Test setup:	SS EUT  Divider  Temperature & Humidity Chamber  Power Source
Test procedure:	<ol> <li>Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage.</li> <li>Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency.</li> <li>Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change.</li> </ol>
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed



## **Measurement Data(worst case):**

## LTE Band 4 part:

Reference Frequency: LTE Band 4(10MHz) Middle channel=20175 channel=1732.50MHz					
Temperature (°C)	Power supplied	Frequency error		Limit (nnm)	Result
	(Vdc)	Hz	ppm	Limit (ppm)	Result
		QPSK			
	4.35	83	0.047908	±2.5	Pass
25	3.80	70	0.040404		
	3.50	58	0.033478		
		16QAM			
25	4.35	79	0.045599	±2.5	Pass
	3.80	60	0.034632		
	3.50	56	0.032323		
Note: Only the worst cas	se shown in the report.				

Reference Fre	equency: LTE Band 1	3(10MHz) Mid	dle channel=2323	0 channel=728.0	0MHz
Temperature (℃)	Power supplied	Frequency error		Limit (nnm)	Result
	(Vdc)	Hz	ppm	Limit (ppm)	Result
		QPSK			
25	4.35	88	0.120879	±2.5	Pass
	3.80	73	0.100275		
	3.50	66	0.090659		
		16QAM			
25	4.35	86	0.118132	±2.5	Pass
	3.80	70	0.096154		
	3.50	59	0.081044		